



RQ3E180AJTB Information



For Reference Only

Part Number RQ3E180AJTB

Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 18A HSMR8

Package 8-PowerVDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RQ3E180AJTB Specifications

Manufacturer Part Number	RQ3E180AJTB
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	18A (Ta), 30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs(th) (Max) @ Id	1.5V @ 11mA
Gate Charge (Qg) (Max) @ Vgs	39nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	4290pF @ 15V
Vgs (Max)	±12V
FET Feature	-
Power Dissipation (Max)	2W (Ta), 30W (Tc)
Rds On (Max) @ Id, Vgs	4.5 mOhm @ 18A, 4.5V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSMT (3.2x3)
Package / Case	8-PowerVDFN
	Report errors?

RQ3E180AJTB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RQ3E180AJTB Payment Methods



















RQ3E180AJTB Shipping Methods













If you have any question about RQ3E180AJTB, please do not hesitate to contact us!

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